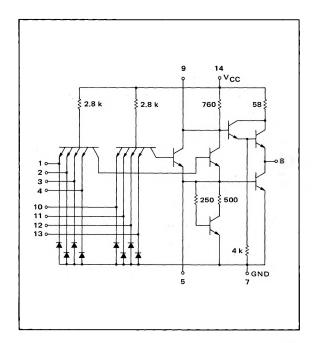
MC3100/MC3000 series

EXPANDABLE 2-WIDE 4-INPUT "AND-OR-INVERT" GATE

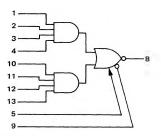
MC3134F · MC3034F MC3134L · MC3034L, P

(54H55J)

(74H55J, N)



This device consists of two 4-input AND gates ORed together and inverted. The emitter and collector nodes of the OR stage are brought out to provide expansion capability to a 6-wide AOI gate using the MC3130/3030 or MC3118/3018 expanders.



Positive Logic:

8 = (1 • 2 • 3 • 4) + (10 • 11 • 12 • 13) + (Expanders)

Negative Logic:

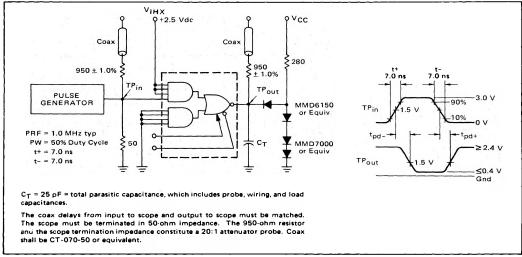
 $8 = (1 + 2 + 3 + 4) \bullet (10 + 11 + 12 + 13) \bullet (Expanders)$

Input Loading Factor = 1 Output Loading Factor = 10 Total Power Dissipation = 30 mW typ/pkg Propagation Delay Time = 7.0 ns typ

Pin numbers for the 54H55F/74H55F device are shown in the chart. These devices are available on special request.

DEVICE						PIN	ΝU	MBE	RS					
MC3134F,L/3034F,L,P	1	2	3	4	5	6	7	8	9	10	11	12	13	14
54H55F/74H55F	14	1	2	3	9	10	11	12	13	5	6	7	8	4

SWITCHING TIME TEST CIRCUIT AND WAVEFORMS



See General Information section for packaging.

MC3134, MC3034 (continued)

ELECTRICAL CHARACTERISTICS Test procedures are shown for only one input of the gate under test. To complete testing, sequence through remaining inputs.

	1		_											TEST	TEST CURRENT/VOLTAGE VALUES (All Temperatures)	L/VOLTA	GE VAL	UES (All	Temper	atures)							
13	1		_					1				MM				Ohms	SI				>	Volts					
 n								L	_i	_ ₅	<u>.</u> E	٩	_x _x	lx2 lx3	3 X4	A REX	@	V _{EX} ®	>~	V _{RH}	>=	V _{IH} X	V _{II}	, S	V _{CC1} V	V _{ссн}	
							Z	MC3134	20	-2.0	1.0	-10 0	0.7 0.	0.32 -0.32	32 0.47	-		1.4 0.4	-	4.0	2.0	2.4	1	2.0	4.5	5.5	
							N	MC3034	20	-2.0	1.0	-10 1	1.1 0.	0.57 -0.57	57 0.6	6 63	Н	1.4 0.4	4 2.5	4.0	2.0	2.4	8.0	5.0 4	4.75 5	5.25	
		Pin	MC31	MC3134 Test Limits -55 to +125°C	imits 5°C	MC3	MC3034 Test Limits	Limits				7	=	TEST CURRENT/VOLTAGE APPLIED TO PINS LISTED BELOW	ENT/VOL	TAGE AF	PLIED	O PINS	LISTED I	SELOW:		-					
Characteristic	Symbol	Test	Min	Max	Unit	Min	Max	Unit	_6	_8		ا ا	-x -x	lx2 lx3	l _{x4}	_	R _{EX} ®	V _{EX} ⊙	>"	V _{RH}	>=	VIHX	>"	νς,	Vccı	V ССН	Gnd
Input Forward Current	T _H	-		-2.0	mAdc	, I	-2.0	mAde				-	,	!	-	'	'	-	,	2, 3, 4					,	14	7
Leakage Current	^I RI	1		20	μAdc		20	μAdc		1.		-			1	1	-	-	-		1	'		, 1		14 2	2,3,4,7, 10,11,12,13
Breakdown Voltage	BV	1	5.5**		mVdc	5.5**		mVdc	-	-	-	ļ.,		1	-	1	-	-	-	1.5	1	1,		1	1	14 2	2,3,4,7,
Clamp Voltage	v _D	-		-1.5**	Vdc	-	-1.5**	Vdc	,		•	1		-	•	-	_	1	'		'			1	14		7
Expander Input Current	^I EX	Θ 6		-5.85	mAdc		-6.3	mAdc		7		,		1		'	5,9	6	'	1	. 1	1		,	14	- 10,	1,2,3,4,7,
Base-Emitter Voltage	VBE	5 @	1	1.0	Vdc		1.0	Vdc	80		,	- 2,	6	1	,		-	1		1	-		1	,	14	- 10	1,2,3,4,7,
Output Output Voltage	TO _A	80	ya Tina	0.4	Vdc	1 - 1	9.4	Vdc			,			1	,			, 1	1		1,2,	-	1	1	14	- 7,1	7,10,11,12,13
		@ @		0.4	Vdc	1	0.4	Vdc	00	1	1."	-	-	-	- ro			1		. 1.	3,4,	ı		1	14	- 10	1,2,3,4,7, 10,11,12,13
	МОМ	80	2.4		Vdc	2.5	1	Vdc		80	1			,	-	'	-	-	'	2,3,4,	. 89	1	1,10	-	14	1	-
		89	2.4		Vdc	2.5	1	Vdc	ı	80	1		1	6	1		1		,	1	1	,		-1	14	- 10	1,2,3,4,7, 10,11,12,13
Short-Circuit Current	rsc T	8	-40	-100	mAdc	-40	-100	mAdc						1		'	'	1	,	٠.	ì				1	14 1,	1,2,3,4,7, 10,11,12,13
Power Requirements Power Supply Drain	наат	14	1	12	mAdc		12	mAdc			- 137				•		'	×	•	1,2,3,4,10,	3,		1	,	1	14	4
	Ippl	14	1	6.4	mAdc		6.4	mAdc	1		1			1	-				1	1	•	1,		1	1	14 10	1,2,3,4,7,
Switching Parameters						-		_	Pulse I	Pulse Out			3													-	
Turn-On Delay	t **	1,8		**11	su	1	11**	su		80	-,		-	'		3 1			1	1	1	2,3,4	1.	14	1	- 7,10	7,10,11,12,13
Turn-Off Delay	** +bq	1,8		11**	ns	,	11**	su	-	8		-		-	-		-	1	1	,	-	2,3,4	-	14	,	- 7,10	7,10,11,12,13

** Tested only at 25°C

(1) See Figure 1.(2) See Figure 2.(3) See Figure 3.